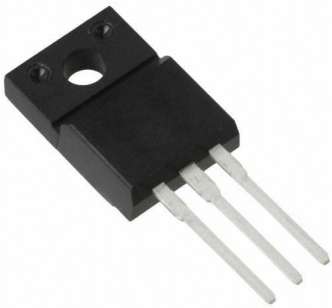


2SC57390P Datasheet

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DiGi Electronics Part Number	2SC57390P-DG
Manufacturer	Panasonic Electronic Components
Manufacturer Product Number	2SC57390P
Description	TRANS NPN 60V 3A TO220D-A1
Detailed Description	Bipolar (BJT) Transistor NPN 60 V 3 A 180MHz 2 W T hrough Hole TO-220D-A1



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

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Purchase and inquiry

Manufacturer Product Number:

2SC57390P

Series:

-

Transistor Type:

NPN

Voltage - Collector Emitter Breakdown (Max):

60 V

Current - Collector Cutoff (Max):

100 μ A

Power - Max:

2 W

Operating Temperature:

150°C (TJ)

Package / Case:

TO-220-3 Full Pack

Base Product Number:

2SC573

Manufacturer:

Panasonic Electronic Components

Product Status:

Obsolete

Current - Collector (Ic) (Max):

3 A

Vce Saturation (Max) @ Ib, Ic:

500mV @ 375mA, 3A

DC Current Gain (hFE) (Min) @ Ic, Vce:

160 @ 1A, 4V

Frequency - Transition:

180MHz

Mounting Type:

Through Hole

Supplier Device Package:

TO-220D-A1

Environmental & Export classification

Moisture Sensitivity Level (MSL):

1 (Unlimited)

HTSUS:

8541.29.0075

ECCN:

EAR99

2SC5739

Silicon NPN epitaxial planar type

Power supply for Audio & Visual equipments
such as TVs and VCRs
Industrial equipments such as DC-DC converters

■ Features

- High-speed switching (t_{stg} : storage time/ t_f : fall time is short)
- Low collector-emitter saturation voltage $V_{CE(sat)}$
- Superior forward current transfer ratio h_{FE} linearity
- TO-220D built-in: Excellent package with withstand voltage 5 kV guaranteed

■ Absolute Maximum Ratings $T_C = 25^\circ C$

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V_{CBO}	60	V
Collector-emitter voltage (Base open)	V_{CEO}	60	V
Emitter-base voltage (Collector open)	V_{EBO}	6	V
Collector current	I_C	3	A
Peak collector current *	I_{CP}	6	A
Collector power dissipation	P_C	20	W
	$T_a = 25^\circ C$	2.0	
Junction temperature	T_j	150	$^\circ C$
Storage temperature	T_{stg}	-55 to +150	$^\circ C$

Note) *: Non-repetitive peak collector current

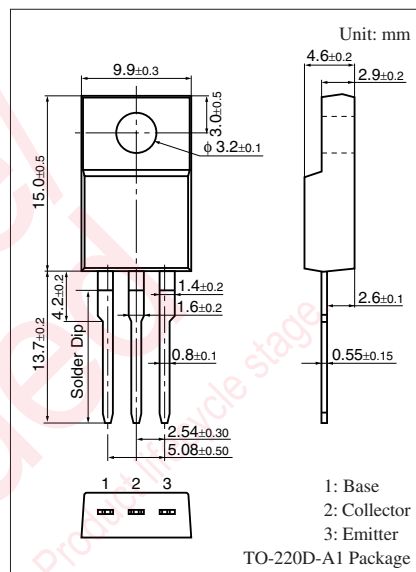
■ Electrical Characteristics $T_C = 25^\circ C \pm 3^\circ C$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector-emitter voltage (Base open)	V_{CEO}	$I_C = 10 \text{ mA}, I_B = 0$	60			V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = 60 \text{ V}, I_E = 0$			100	μA
Collector-emitter cutoff current (Base open)	I_{CEO}	$V_{CE} = 60 \text{ V}, I_B = 0$			100	μA
Emitter-base cutoff current (Collector open)	I_{EBO}	$V_{EB} = 6 \text{ V}, I_C = 0$			1	mA
Forward current transfer ratio	h_{FE1} *	$V_{CE} = 4 \text{ V}, I_C = 1 \text{ A}$	120		320	—
	h_{FE2}	$V_{CE} = 4 \text{ V}, I_C = 3 \text{ A}$	40			
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 3 \text{ A}, I_B = 0.375 \text{ A}$			0.5	V
Transition frequency	f_T	$V_{CE} = 10 \text{ V}, I_C = 0.1 \text{ A}, f = 10 \text{ MHz}$		180		MHz
Turn-on time	t_{on}	$I_C = 1 \text{ A}, \text{Resistance loaded}$		0.2	0.3	μs
Storage time	t_{stg}	$I_{B1} = 0.1 \text{ A}, I_{B2} = -0.1 \text{ A}$		0.55	0.70	μs
Fall time	t_f		$V_{CC} = 50 \text{ V}$		0.10	0.15

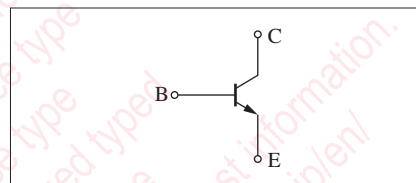
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

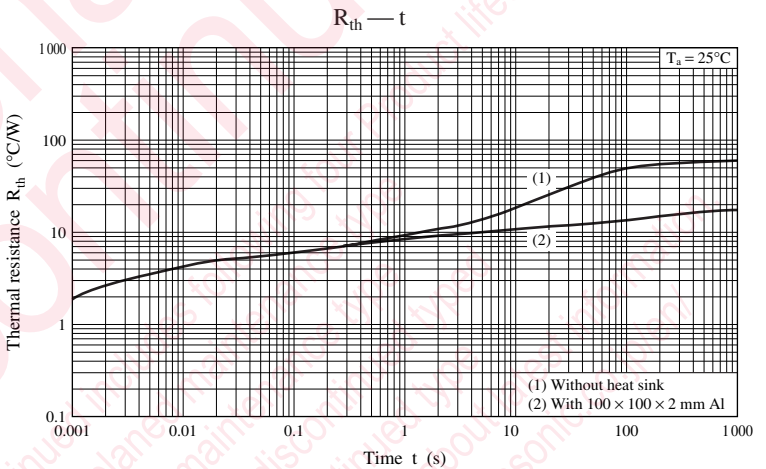
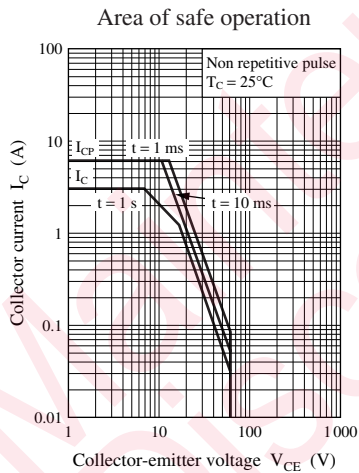
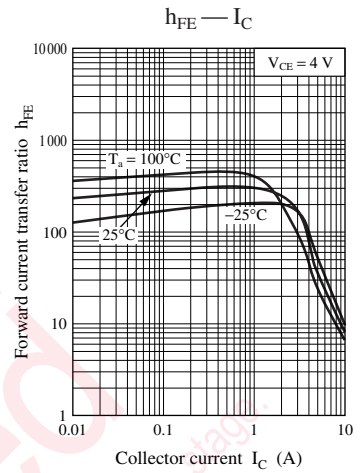
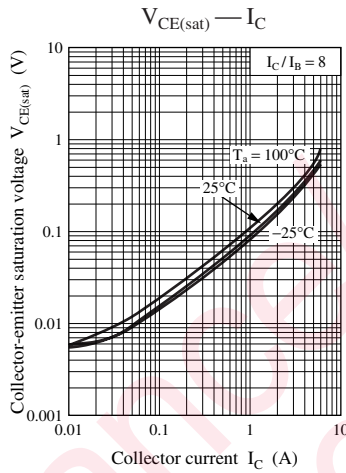
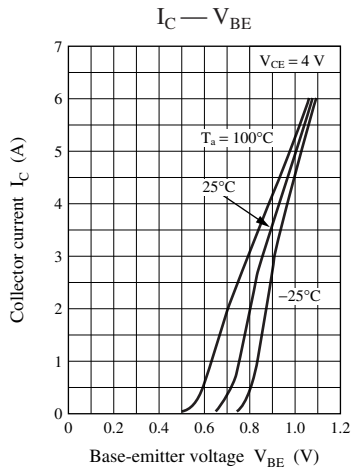
2. *: Rank classification

Rank	Q	P
h_{FE1}	120 to 250	160 to 320



Internal Connection





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